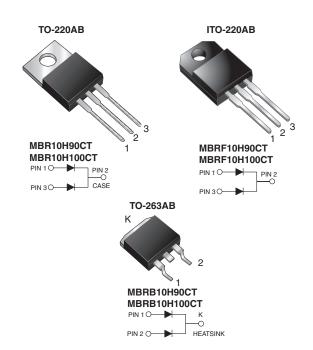




Vishay General Semiconductor

Dual Common-Cathode High-Voltage Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



PRIMARY CHARACTERISTICS					
I _{F(AV)}	5 A x 2				
V _{RRM}	90 V, 100 V				
I _{FSM}	150 A				
V _F	0.61 V				
I _R	3.5 μΑ				
T _J max.	175 °C				

FEATURES

Guardring for overvoltage protection



Low forward voltage drop

Low leakage current

High forward surge capability

High frequency operation

 Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)

 Solder Dip 260 °C, 40 s (for TO-220AB and ITO-220AB package)

 Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2

whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR10H90CT	MBR10H100CT	UNIT		
Maximum repetitive peak reverse voltage	V_{RRM}	90	100	V		
Working peak reverse voltage	V_{RWM}	90	100	V		
Maximum DC blocking voltage	V_{DC}	90	100	V		
Maximum average forward rectified current at T _C = 105 °C total device per diode	I _{F(AV)}	10 5.0		Α		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	150		Α		
Peak repetitive reverse current per diode at t _p = 2 μs, 1 kHz	I _{RRM}	0.5		Α		
Voltage rate of change (rated V _R)	dV/dt	dt 10 000		V/µs		
Operating junction and storage temperature range	T _J , T _{STG}	- 65 to + 175		°C		
Isolation voltage (ITO-220AB only) from terminals to heatsink t = 1 min		1500		V		

Document Number: 88668 Revision: 08-Nov-07

MBR(F,B)10H90CT & MBR(F,B)10H100CT

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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT		
Maximum instantaneous forward voltage per diode (1)	$I_{\rm F} = 10 {\rm A}$	$T_J = 25 ^{\circ}\text{C}$ $T_J = 125 ^{\circ}\text{C}$ $T_J = 25 ^{\circ}\text{C}$ $T_J = 125 ^{\circ}\text{C}$	V_{F}	0.76 0.61 0.85 0.71	>		
Maximum reverse current per diode at working peak reverse voltage ⁽¹⁾		T _J = 25 °C T _J = 100 °C	I _R	3.5 4.5	μA mA		

Note:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance per diode	$R_{ hetaJC}$	2.2	5.2	2.2	°C/W

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR10H100CT-E3/45	1.85	45	50/tube	Tube		
ITO-220AB	MBRF10H100CT-E3/45	1.79	45	50/tube	Tube		
TO-263AB	MBRB10H100CT-E3/45	1.35	45	50/tube	Tube		
TO-263AB	MBRB10H100CT-E3/81	1.35	81	800/reel	Tape reel		
TO-220AB	MBR10H100CTHE3/45 (1)	1.85	45	50/tube	Tube		
ITO-220AB	MBRF10H100CTHE3/45 (1)	1.79	45	50/tube	Tube		
TO-263AB	MBRB10H100CTHE3/45 (1)	1.35	45	50/tube	Tube		
TO-263AB	MBRB10H100CTHE3/81 (1)	1.35	81	800/reel	Tape reel		

Note:

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

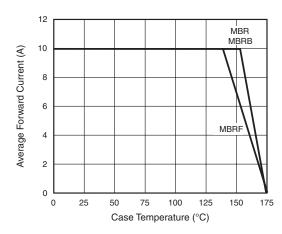


Figure 1. Forward Derating Curve Per Diode

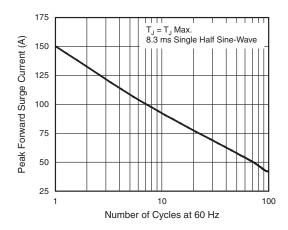


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

⁽¹⁾ Automotive grade AEC Q101 qualified





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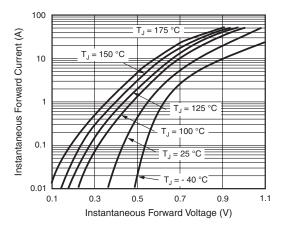


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

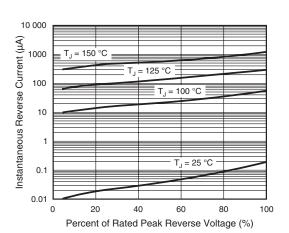


Figure 4. Typical Reverse Characteristics Per Diode

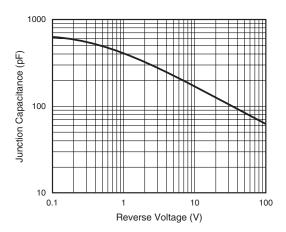


Figure 5. Typical Junction Capacitance Per Diode

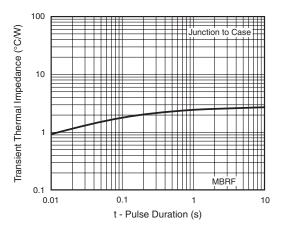


Figure 6. Typical Transient Thermal Impedance Per Diode

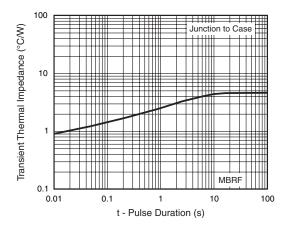


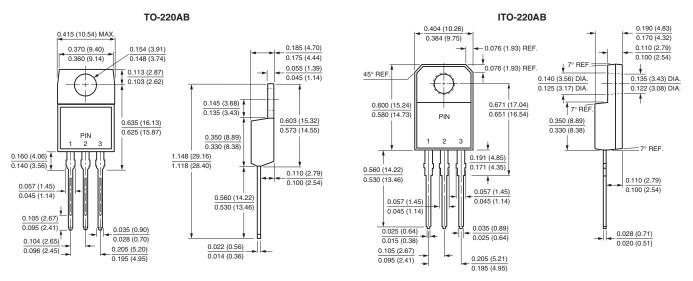
Figure 7. Typical Transient Thermal Impedance Per Diode

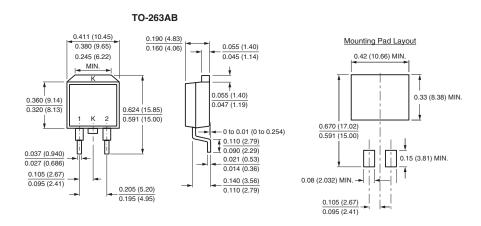
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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Document Number: 91000 www.vishay.com
Revision: 11-Mar-11 1